NSN 5961-00-923-6076

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-923-6076
Inclosure Material:
Metal
Overall Length:
0.450 inches
Overall Diameter:
0.875 inches
Mounting Facility Quantity:
2
Mounting Method:
Unthreaded hole
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
50.0 breakover voltage, dc
Current Rating Per Characteristic:
260.00 amperes forward current, average absolute
Power Rating Per Characteristic:
5.0 watts small-signal input power, common-collector blank
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius junction
Terminal Type And Quantity:
2 tab, solder lug and 1 case
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0